



HLTYH252012

FEATURES 特性

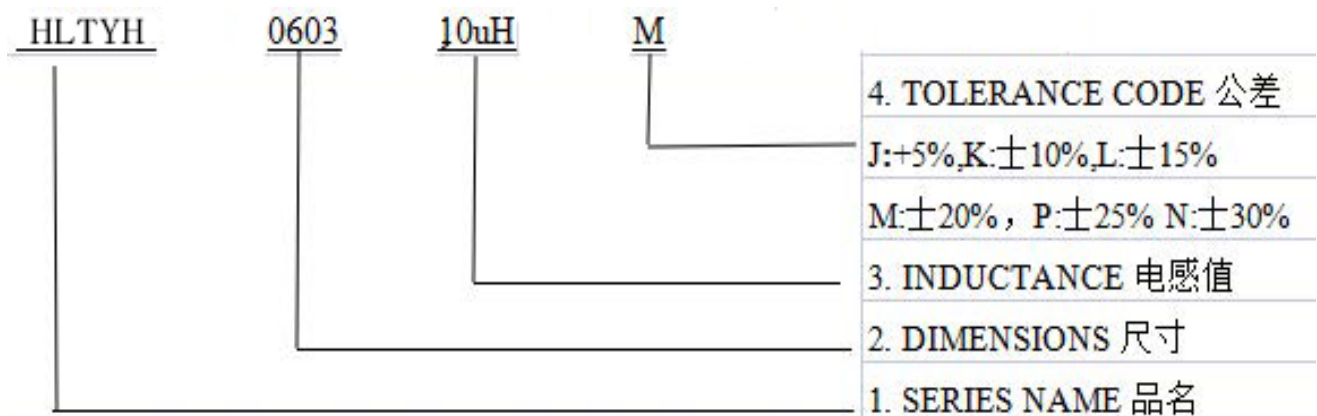
- 1.Magnetic shield structure, closed magnetic circuit, strong anti-electromagnetic interference, ultra-low buzzer, high-density installation. 磁屏蔽结构,闭合磁路,抗电磁干扰强,超低蜂鸣声,可高密度安装.
- 2.Small size, large current, range up to 60A, in high frequency and high temperature environment to maintain excellent temperature rise current and saturation current characteristics.小体积,大电流,范围可到60A,在高频和高温环境下保持优良的温升电流及饱和电流特性.
- 3.Low loss alloy powder die-casting, low resistance. Strong structure, high product accuracy.低损耗合金粉末压铸,低电阻.结构牢固,产品精准度高.
- 4.Wide operating frequency range, up to 5MHz or more. Halogen-free environmental protection products.工作频率范围广,可达5MHz以上.无卤环保产品.

APPLICATIONS 用途

1. PAD/Notebook/Desktop/Server applications PAD, 笔记本电脑, 台式机, 服务器,
2. DC/DC converter DC/DC转换器

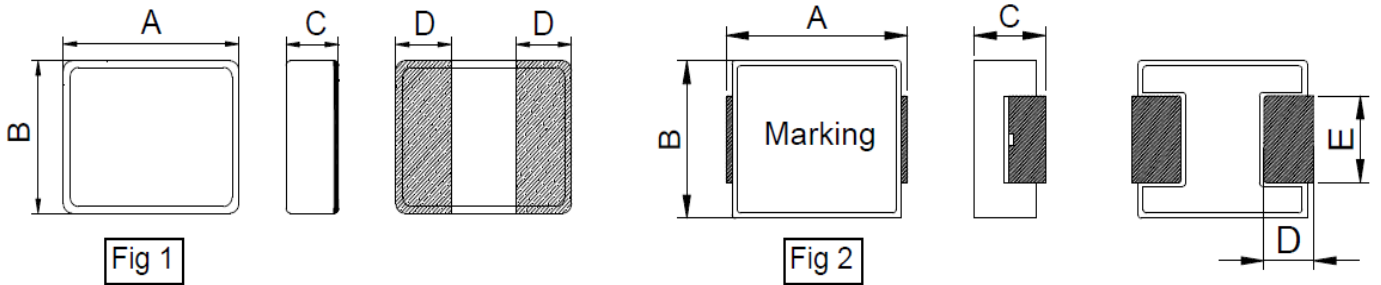
Product title	Size (LxWxH)	Inductance	Rated current
HLTYH252012	2.5±0.2mm/2.0±0.2mm/1.2mm Max	0.33μH~2.2μH	4.40A~2.20A

PART NUMBERING SYSTEM

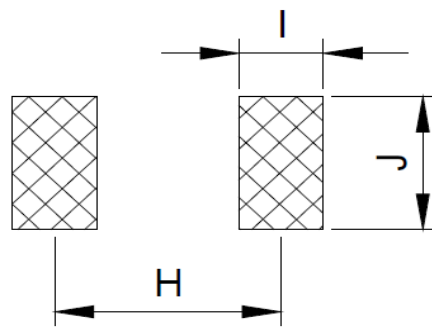




SHAPES AND DIMENSIONS 外形尺寸 (Unit:mm)



TYPE(型号)	A	B	C	D	E	Fig
HLTYH252012	2.5±0.2	2.0±0.2	1.2 Max	0.8±0.3	/	1



TYPE(型号)	H	I	J
HLTYH252012	2	1.2	2.2



SPECIFICATION TABLE:

PART NUMBER	INDUCTANCE (μH)	DCR (mΩ) @25°C		Heat Rating Current DC Amps. Idc (A)	Saturation Current DC Amps. Isat (A)
		Typical	Maximum	Typical	Typical
HLTYH252012- 0.33uH/M	0.33±20%	20.0	24.0	4.40	6.60
HLTYH252012- 0.47uH/M	0.47±20%	24.0	29.0	4.10	5.50
HLTYH252012- 0.68uH/M	0.68±20%	27.0	36.0	3.50	5.10
HLTYH252012- 1uH/M	1±20%	38.0	46.0	3.10	4.10
HLTYH252012- 1.5uH/M	1.5±20%	56.0	67.0	2.60	3.00
HLTYH252012- 2.2uH/M	2.2±20%	76.0	91.0	2.20	2.80

Remark:

All test data is reference to 25°C ambient.

Test Condition : 1MHz , 1Vrms

Idc : DC current (A) that will cause an approximate Δ T of 40°C

Isat : DC current (A) that will cause L0 to drop approximately 30% Typ.

Operat between temperature range -40°C to +125°C (Including self - temperature rise)

Absolute maximum voltage: DC 25V